TOSHIBA Field Effect Transistor Silicon N Channel MOS Type ( $\pi$ -MOSIII)

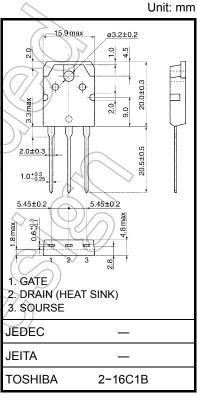
# 2SK2613

Switching Regulator Applications, DC-DC Converter and Motor Drive Applications

- Low drain-source ON-resistance: RDS (ON) =  $1.4 \Omega$  (typ.)
- High forward transfer admittance:  $|Y_{fs}| = 6.0 \text{ S (typ.)}$
- Low leakage current:  $I_{DSS} = 100 \mu A \text{ (max) (V}_{DS} = 800 \text{ V)}$
- Enhancement-model:  $V_{th} = 2.0 \text{ to } 4.0 \text{ V (VDS} = 10 \text{ V, ID} = 1 \text{ mA)}$

### Absolute Maximum Ratings (Ta = 25°C)

Characteristics			Symbol	Rating	Unit
Drain-source voltage			$V_{DSS}$	1000	$\langle \psi \rangle$
Drain-gate voltage ( $R_{GS} = 20 \text{ k}\Omega$ )			$V_{DGR}$	1000	)>/
Gate-source voltage			$V_{GSS}$	±30	<b>\</b>
Drain current	DC	(Note 1)	ID	8	A
	Pulse	(Note 1)	I <sub>DP</sub>	24	A
Drain power dissipation (Tc = 25°C)			PD	150	W
Single pulse avalanche energy (Note 2)			E <sub>AS</sub>	910	mJ
Avalanche current			I <sub>AR</sub>	)) 8	Α
Repetitive avalanche energy (Note 3)			EAR	15	mJ
Channel temperature			T <sub>ch</sub>	150	Ç
Storage temperature range			Tstg	–55 to 150	~e

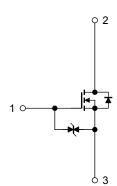


Weight: 4.6 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

#### Thermal Characteristics

Characteristics	Symbol	Max	Unit
Thermal resistance, channel to case	Rth (ch-c)	0.833	°C/W
Thermal resistance, channel to ambient	R <sub>th (ch-a)</sub>	50	°C/W



- Note 1: Please use devices on condition that the channel temperature is below 150°C.
- Note 2:  $V_{DD} = 90 \text{ V}$ ,  $T_{ch} = 25^{\circ}\text{C}$ , L = 26.3 mH,  $R_G = 25 \Omega$ ,  $I_{AR} = 8 \text{ A}$
- Note 3: Repetitive rating: Pulse width limited by max junction temperature

This transistor is an electrostatic sensitive device. Please handle with caution.

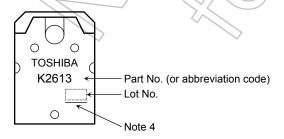
## **Electrical Characteristics (Ta = 25°C)**

Chara	cteristics	Symbol	Test Condition	Min	Тур.	Max	Unit		
Gate leakage curr	ent	I <sub>GSS</sub>	$V_{GS} = \pm 30 \text{ V}, V_{DS} = 0 \text{ V}$	_	_	±10	μА		
Gate-source break	kdown voltage	V (BR) GSS	$I_G = \pm 10 \ \mu A, \ V_{DS} = 0 \ V$	±30	_	_	V		
Drain cut-OFF cur			V <sub>DS</sub> = 800 V, V <sub>GS</sub> = 0 V	/	_	100	μА		
Drain-source brea	Orain-source breakdown voltage		$I_D = 10 \text{ mA}, V_{GS} = 0 \text{ V}$	1000		_	V		
Gate threshold voltage		V <sub>th</sub>	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 1 mA	2.0	))	4.0	V		
Drain-source ON resistance		R <sub>DS (ON)</sub>	V <sub>GS</sub> = 10 V, I <sub>D</sub> = 4 A		1.4	1.7	Ω		
Forward transfer admittance		Y <sub>fs</sub>	V <sub>DS</sub> = 20 V, I <sub>D</sub> = 4 A	2.0	6.0	_	S		
Input capacitance		C <sub>iss</sub>		)	2000	_			
Reverse transfer capacitance		C <sub>rss</sub>	$V_{DS} = 25 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$	_	30	_	pF		
Output capacitance		Coss			200				
Switching time	Rise time	t <sub>r</sub>	10 V D=4A	- (	20	<u>\</u>	<u>&gt;</u>		
	Turn-ON time	t <sub>on</sub>	0 V		40	) —	ns		
	Fall time	t <sub>f</sub>	G \$ R <sub>L</sub> = 100 Ω		30				
	Turn-OFF time	t <sub>off</sub>	Duty $\leq$ 1%, t <sub>W</sub> = 10 μs	) –	100	_			
Total gate charge (gate-source plus gate-drain)		Qg			65		_		
Gate-source charge		Qgs	$V_{DD} \approx 400 \text{ V}, V_{GS} = 10 \text{ V}, I_{D} = 8 \text{ A}$		40		nC		
Gate-drain ("miller") charge		Qgd	\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \		25				

## Source-Drain Ratings and Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Continuous drain reverse current (Note 1)	I <sub>DR</sub>	_	_	_	8	Α
Pulse drain reverse current (Note 1)	IDRP		_	_	24	Α
Forward voltage (diode)	V <sub>DSF</sub>	I <sub>DR</sub> = 8 A, V <sub>GS</sub> = 0 V	_	_	-1.9	V
Reverse recovery time	∕> t <sub>rr</sub>	$I_{DR} = 8 \text{ A}, V_{GS} = 0 \text{ V},$	_	1600	_	ns
Reverse recovery charge	Qrr	dI <sub>DR</sub> /dt = 100 A/μs		24	_	μС

#### Marking

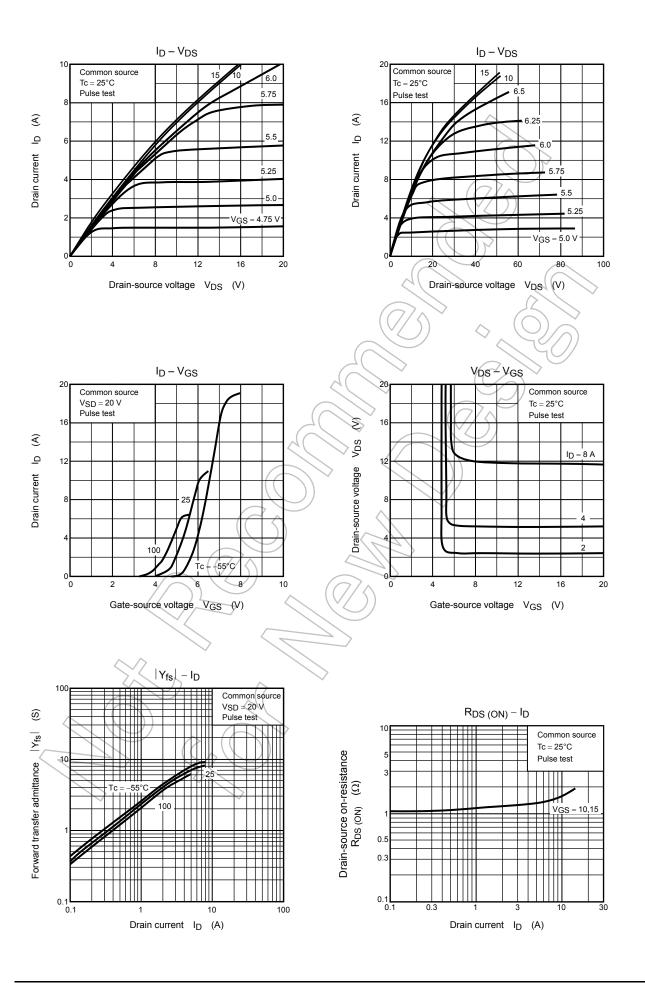


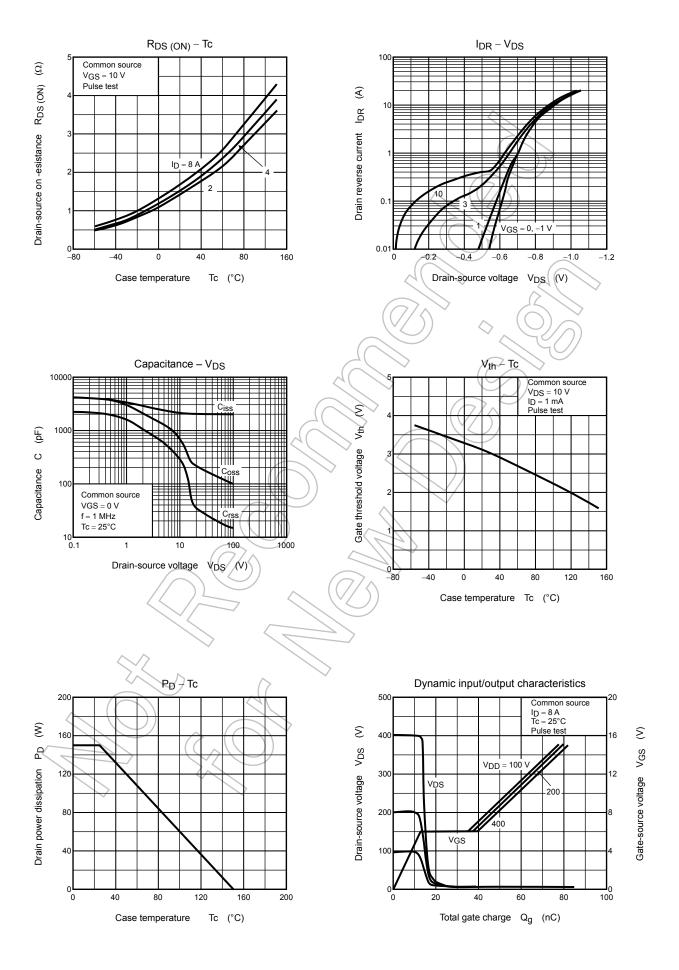
Note 4: A line under a Lot No. identifies the indication of product Labels.

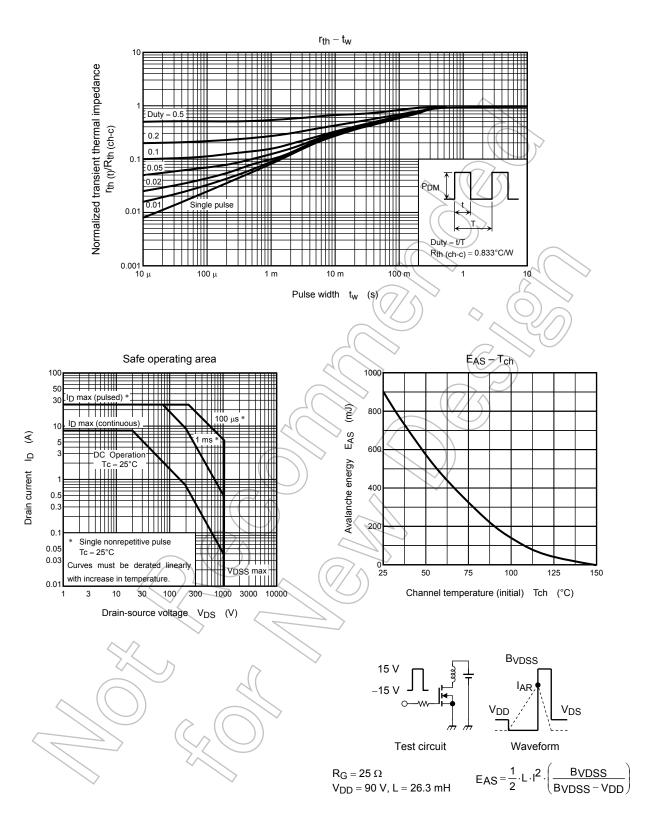
Not underlined: [[Pb]]/INCLUDES > MCV

Underlined: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product. The RoHS is the Directive 2011/65/EU of the European Parliament and of the Council of 8 June 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.







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